# AN ANALYSIS PERFORMANCE OF A SINGLE-PHASE INDUCTION MOTOR USING SINGLE-PHASE MATRIX CONVERTER

LIYANA BT SA'ARI

## FACULTY OF ELECTRICAL ENGINEERING UNIVERSITI TEKNOLOGI MARA MALAYSIA

### ACKNOWLEDGEMENTS

First of all, I really would like to thank to Allah s.w.t for His approval and blessing that made all this happened and came true. Nothing can be done without His permission. Allhamdulillah.

A special and most honoured gratitude to my supervisor Cik Nor Farahaida Bt Abd Rahman for her guidance, teachings and support throughout this project. I am truly honoured and humble to have her as my supervisor because his knowledge and expertise is very vast and wide. I am beyond doubt enjoyed the challenge of discussing and debating various aspects and topics regarding my project with him which later helped me improve my final project and knowledge about it.

I would also like to thank Prof Madya Dr Ngah Ramzi and En Rahimi Baharom for the evaluation of my technical paper presentation, technical paper and final report for this project.

Special thanks to my acquaintances for helping me with their precious suggestions and supports through out the completion of this project. Your kindness will be embedded in my heart forever.

iv

i ai

## ABSTRACT

This paper presents an analysis performance of a Single Phase Capacitor-Start Induction Motor using matrix converter. It can be proved that, Single Phase Induction Motor using Single Phase Matrix Converter able to produce better starting current, starting torque and input voltage utilization. Matrix converter is used to convert power from ac fixedfrequency fixed-voltage to ac variable-frequency variable-voltage without any intermediate dc link. Sinusoidal Pulse Width Modulation (SPMW) technique is used to control the self-commutated device, IGBT. Safe commutation strategy was implemented to avoid voltage spike due to inductive load. Simulation result using SimPower system blocks is presented in this paper.

# TABLE OF CONTENT

| CHAPTER | TITLE                            |    | PAGE |
|---------|----------------------------------|----|------|
|         | DECLARATION OF THESIS            |    | ii.  |
|         | ACKNOWLEDGEMENT                  |    | iv   |
|         | ABSTRACT                         | •  | v    |
|         | TABLE OF CONTENT                 | ч. | vi   |
|         | LIST OF TABLES                   |    | ix   |
|         | LIST OF FIGURES                  |    | X    |
| 1       | INTRODUCTION                     |    |      |
|         | 1.1 Overview                     | ٤  | 1    |
|         | 1.2 Problem                      |    | 2    |
|         | 1.3 Objective                    |    | 3    |
|         | 1.4 Scope of Project             |    | 3    |
|         | 1.5 Research Methodology         |    | 4    |
| 2       | LITERATURE REVIEW                |    |      |
|         | 2.1 Introduction                 |    | 6    |
|         | 2.2 Single-Phase AC-AC Converter |    | 6    |
|         | 2.3 Matrix Converter             |    | 7    |
|         | 2.4 Commutation Strategy         |    | 8    |
|         | 2.5 SPWM Technique               |    | 10   |
| - تورد  |                                  |    |      |

### **CHAPTER 1**

### **INTRODUCTION**

#### **1.1 OVERVIEW**

Power Electronics are based primarily on the switching of the power semiconductor devices. Power electronics application such as energy conservation (compressor, air condition) can save the energy 15-20% of electricity. For example, variable speed compressor air-conditioning systems save up to 30% of energy compared to conventional thermostat-controlled system. With the development of power semiconductor technology, the power handling capabilities and the switching speed of the power devices have improved tremendously [1].

Power semiconductor can be regarded as the brain of the modern power electronics equipment. Power semiconductor devices can be operated as switches by controlling the signals to the gate terminal of the thyristor or base terminal of bipolar transistor. The power semiconductor devices can be categorized into three groups, that is; diodes, thyristor and controllable switches. In this thesis, the focus is on controllable switches that can be turned on and off by low-power control signals such as BJT, MOSFET, IGBT. They are commonly used as power switches in converter designs. These controllable switches are very important for control of voltage and current. It can be divided into three general categories; natural commutation, phase control and ON-OFF controlled device [2].

1